



P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)			
- 30	0.0075 at V _{GS} = - 10 V	- 15			
	0.011 at V _{GS} = - 4.5 V	- 12.3			

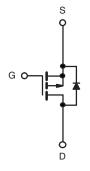
FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET® Power MOSFET

HALOGEN FREE

APPLICATIONS

- Notebook
 - Load Switch
 - Battery Switch



P-Channel MOSFET

	SO-8		
S 1 S 2 S 3 G 4		8 7 6 5	D D D
	Top View		

Ordering Information: Si4413ADY-T1-E3 (Lead (Pb)-free) Si4413ADY-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	$T_A = 25 {}^{\circ}C$, unles	ss otherwise n	oted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V _{DS}	- 30		V
Gate-Source Voltage		V_{GS}	± 20		
Continuous Dusin Comment /T 450 90\8	T _A = 25 °C	- I _D	- 15	- 10.5	Δ.
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C		- 11.8	- 8.3	
Pulsed Drain Current		I _{DM}	- 50		Α
Continuous Source Current (Diode Conduction) ^a		I _S	- 2.7	- 1.36	
	T _A = 25 °C	P _D	3.0	1.5	W
Maximum Power Dissipation ^a	T _A = 70 °C		1.9	0.95	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Marrian Investigation to Ambienta	t ≤ 10 s	R _{thJA}	33	42		
Maximum Junction-to-Ambient ^a	Steady State	' 'thJA	70	84	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	16	21		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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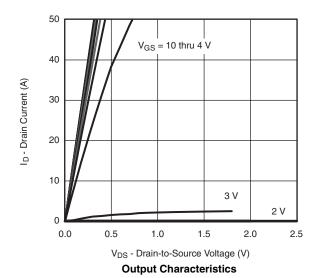
SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions Min.		Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \mu\text{A}$ - 1.0			- 3.0	V	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zara Cata Valtaga Brain Current		V _{DS} = - 30 V, V _{GS} = 0 V			- 1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 30 V, V _{GS} = 0 V, T _J = 70 °C	V, V _{GS} = 0 V, T _J = 70 °C			μΑ	
On-State Drain Current ^a	I _{D(on)}	V _{DS} = - 5 V, V _{GS} = - 10 V	- 30			Α	
	В	V _{GS} = - 10 V, I _D = - 13 A		0.0063	0.0075	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 10 A		0.0083	0.011		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 13 A		50		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 2.7 A, V _{GS} = 0 V		- 0.74	- 1.1	V	
Dynamic ^b							
Total Gate Charge	Q_g			61	95		
Gate-Source Charge	Q _{gs}	$V_{DS} = -15 \text{ V}, V_{GS} = -5 \text{ V}, I_{D} = -13 \text{ A}$		15.5		nC	
Gate-Drain Charge	Q_{gd}			32			
Turn-On Delay Time	t _{d(on)}			21	35		
Rise Time	t _r	V_{DD} = - 15 V, R_L = 15 Ω		18	30	ns	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong\text{-1 A},\text{V}_\text{GEN}=\text{-10 V},\text{R}_\text{G}=\text{6}\;\Omega$		170	260		
Fall Time	t _f			97	150		
Gate Resistance	R_{g}			3.4		Ω	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 2.1 A, dI/dt = 100 A/μs		70	110	ns	

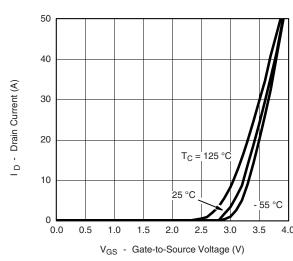
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





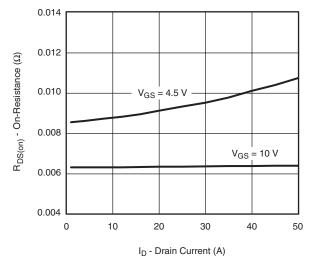
Transfer Characteristics



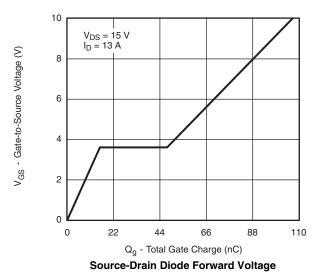




TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



On-Resistance vs. Drain Current



Is - Source Current (A) T_J = 150 °C 10 $T_J = 25$ °C

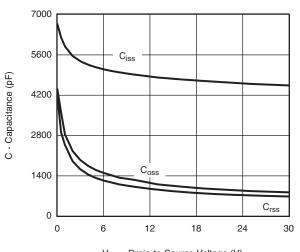
V_{SD} - Source-to-Drain Voltage (V) On-Resistance vs. Junction Temperature

0.6

0.8

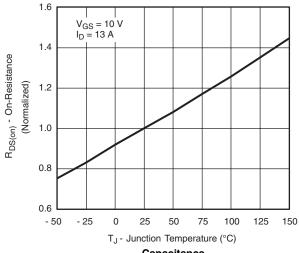
1.0

1.2

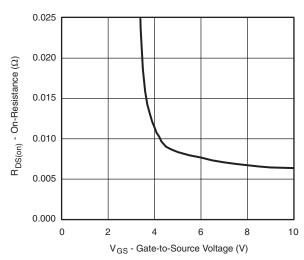


V_{DS} - Drain-to-Source Voltage (V)

Gate Charge



Capacitance



On-Resistance vs. Gate-to-Source Voltage

0.1

0.0

0.2

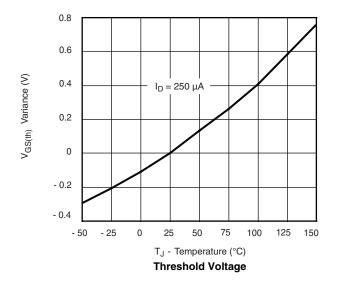
0.4

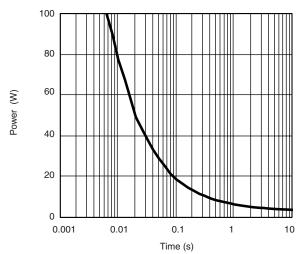
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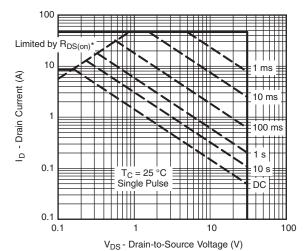
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



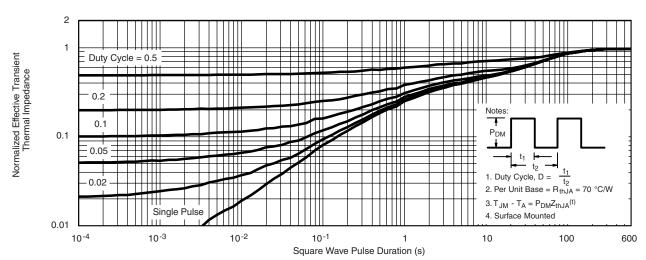


Single Pulse Power, Junction-to-Ambient



 * V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

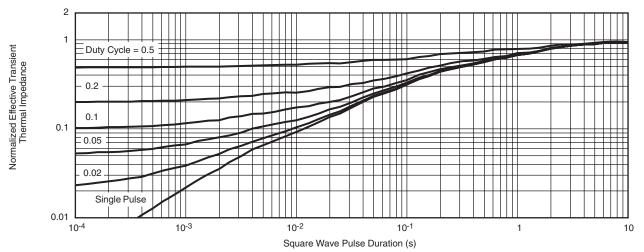
Safe Operating Area, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

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SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







	MILLIM	IETERS	INCHES			
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A ₁	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
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RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)

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